

MM74HC4049 • MM74HC4050 **Hex Inverting Logic Level Down Converter •** **Hex Logic Level Down Converter**

General Description

The MM74HC4049 and the MM74HC4050 utilize advanced silicon-gate CMOS technology, and have a modified input protection structure that enables these parts to be used as logic level translators which will convert high level logic to a low level logic while operating from the low logic supply. For example, 0–15V CMOS logic can be converted to 0–5V logic when using a 5V supply. The modified input protection has no diode connected to V_{CC} , thus allowing the input voltage to exceed the supply. The lower zener diode protects the input from both positive and negative static voltages. In addition each part can be used as a sim-

ple buffer or inverter without level translation. The MM74HC4049 is pin and functionally compatible to the CD4049BC and the MM74HC4050 is compatible to the CD4050BC

Features

- Typical propagation delay: 8 ns
- Wide power supply range: 2V–6V
- Low quiescent supply current: 20 μ A maximum (74HC)
- Fanout of 10 LS-TTL loads

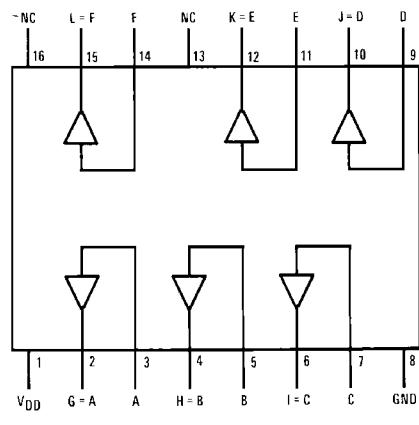
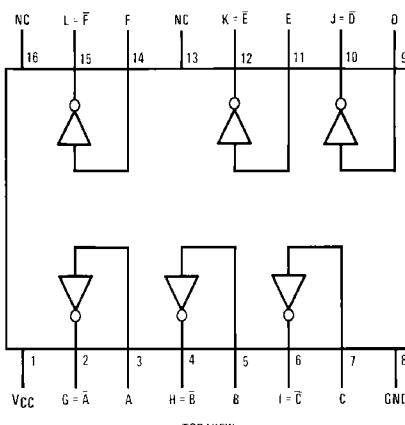
Ordering Code:

Order Number	Package Number	Package Description
MM74HC4094M	M16A	16-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-012, 0.150" Narrow
MM74HC4094SJ	M16D	16-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
MM74HC4094MTC	MTC16	16-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide
MM74HC4094N	N16E	16-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300" Wide
MM74HC4050M	M16A	16-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-012, 0.150" Narrow
MM74HC4050SJ	M16D	16-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
MM74HC4050MTC	MTC16	16-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide
MM74HC4050N	N16E	16-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300" Wide

Devices also available in Tape and Reel. Specify by appending the suffix letter "X" to the ordering code.

Connection Diagrams

Pin Assignments for DIP, SOIC, SOP, and TSSOP



Absolute Maximum Ratings ^(Note 1)		Recommended Operating Conditions						
(Note 2)								
Supply Voltage (V_{CC})	-0.5 to +7.0V			Min Max Units				
DC Input Voltage (V_{IN})	-1.5 to +18V	Supply Voltage (V_{CC})	2 6 V					
DC Output Voltage (V_{OUT})	-0.5 to V_{CC} +0.5V	DC Input Voltage (V_{IN})	0 15 V					
Clamp Diode Current (I_{ZK}, I_{OK})	-20 mA	DC Output Voltage (V_{OUT})	0 V_{CC} V					
DC Output Current, per pin (I_{OUT})	± 25 mA	Operating Temperature Range (T_A)	-40 +85 °C					
DC V_{CC} or GND Current, per pin (I_{CC})	± 50 mA	Input Rise or Fall Times						
Storage Temperature Range (T_{STG})	-65°C to +150°C	(t_r, t_f) $V_{CC} = 2.0V$	1000 ns					
Power Dissipation (P_D)		$V_{CC} = 4.5V$	500 ns					
(Note 3)	600 mW	$V_{CC} = 6.0V$	400 ns					
S.O. Package only	500 mW							
Lead Temperature (T_L)								
(Soldering 10 seconds)	260°C							
		Note 1: Absolute Maximum Ratings are those values beyond which damage to the device may occur.						
		Note 2: Unless otherwise specified all voltages are referenced to ground.						
		Note 3: Power Dissipation temperature derating — plastic "N" package: -12 mW/°C from 65°C to 85°C.						
DC Electrical Characteristics ^(Note 4)								
Symbol	Parameter	Conditions	V_{CC}	$T_A = 25^\circ C$	$T_A = -40^\circ C \text{ to } 85^\circ C$	$T_A = -55^\circ C \text{ to } 125^\circ C$	Units	
				Typ	Guaranteed Limits			
V_{IH}	Minimum HIGH Level Input Voltage		2.0V	1.5	1.5	1.5	V	
			4.5V	3.15	3.15	3.15	V	
			6.0V	4.2	4.2	4.2	V	
V_{IL}	Maximum LOW Level Input Voltage		2.0V	0.5	0.5	0.5	V	
			4.5V	1.35	1.35	1.35	V	
			6.0V	1.8	1.8	1.8	V	
V_{OH}	Minimum HIGH Level Output Voltage $ I_{OUT} \leq 20 \mu A$	$V_{IN} = V_{IH}$ or V_{IL}	2.0V	2.0	1.9	1.9	V	
			4.5V	4.5	4.4	4.4	V	
			6.0V	6.0	5.9	5.9	V	
		$V_{IN} = V_{IH}$ or V_{IL} $ I_{OUT} \leq 4.0 \text{ mA}$	4.5V	4.2	3.98	3.84	3.7	V
		$ I_{OUT} \leq 5.2 \text{ mA}$	6.0V	5.7	5.48	5.34	5.2	V
	V_{OL}	Maximum LOW Level Output Voltage $ I_{OUT} \leq 20 \mu A$	$V_{IN} = V_{IH}$ or V_{IL}	2.0V	0	0.1	0.1	V
			4.5V	0	0.1	0.1	V	
			6.0V	0	0.1	0.1	V	
		$V_{IN} = V_{IH}$ or V_{IL} $ I_{OUT} \leq 4 \text{ mA}$	4.5V	0.2	0.26	0.33	0.4	V
		$ I_{OUT} \leq 5.2 \text{ mA}$	6.0V	0.2	0.26	0.33	0.4	V
I_{IN}		Maximum Input Current	$V_{IN} = V_{CC}$ or GND	6.0V		± 0.1	± 1.0	± 1.0 μA
		$V_{IN} = 15V$	2.0V		± 0.5	± 5	± 5 μA	
I_{CC}	Maximum Quiescent Supply Current	$V_{IN} = V_{CC}$ or GND $ I_{OUT} = 0 \mu A$	6.0V		2.0	20	40 μA	
Note 4: For a power supply of 5V $\pm 10\%$ the worst case output voltages (V_{OH} and V_{OL}) occur for HC at 4.5V. Thus the 4.5V values should be used when designing with this supply. Worst case V_{IH} and V_{IL} occur at $V_{CC} = 5.5V$ and 4.5V respectively. (The V_{IH} value at 5.5V is 3.85V.) The worst case leakage current (I_{IN} , I_{CC} , I_{OZ}) occur for CMOS at the higher voltage and so the 6.0V values should be used.								

AC Electrical Characteristics

$V_{CC} = 5V$, $T_A = 25^\circ C$, $C_L = 15 \text{ pF}$, $t_r = t_f = 6 \text{ ns}$

Symbol	Parameter	Conditions	Typ	Guaranteed Limit	Units
t_{PHL}, t_{PLH}	Maximum Propagation Delay		8	15	ns

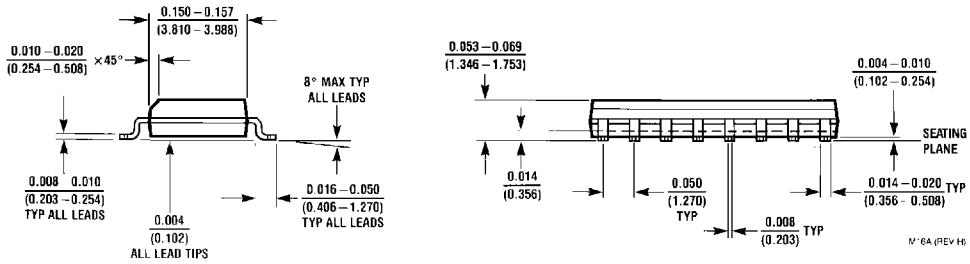
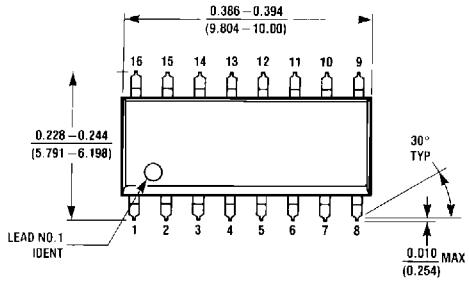
AC Electrical Characteristics

$V_{CC} = 2.0V$ to $6.0V$, $C_L = 50 \text{ pF}$, $t_r = t_f = 6 \text{ ns}$ (unless otherwise specified)

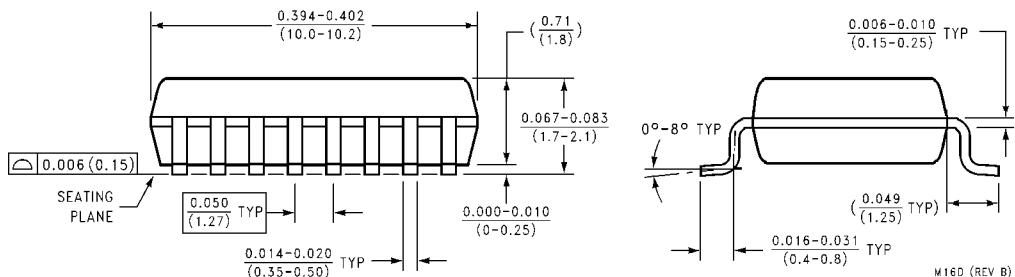
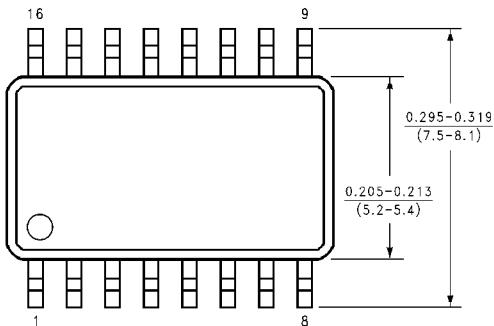
Symbol	Parameter	Conditions	V_{CC}	$T_A = 25^\circ C$			$T_A = -40^\circ \text{ to } 85^\circ C$	$T_A = -55^\circ \text{ to } 125^\circ C$	Units
				Typ	Guaranteed Limits				
t_{PHL}, t_{PLH}	Maximum Propagation Delay		2.0V	30	85	100	130	ns	ns
			4.5V	10	17	20	26	ns	
			6.0V	9	15	18	22	ns	
t_{THL}, t_{TLH}	Maximum Output Rise and Fall Time		2.0V	25	75	95	110	ns	ns
			4.5V	7	15	19	22	ns	
			6.0V	6	13	16	19	ns	
C_{PD}	Power Dissipation Capacitance (Note 5)	(per gate)		25					pF
C_{IN}	Maximum Input Capacitance			5	10	10	10	10	pF

Note 5: C_{PD} determines the no load dynamic power consumption, $P_D = C_{PD} V_{CC}^2 f + I_{CC} V_{CC}$, and the no load dynamic current consumption, $I_S = C_{PD} V_{CC} f + I_{CC}$.

Physical Dimensions inches (millimeters) unless otherwise noted

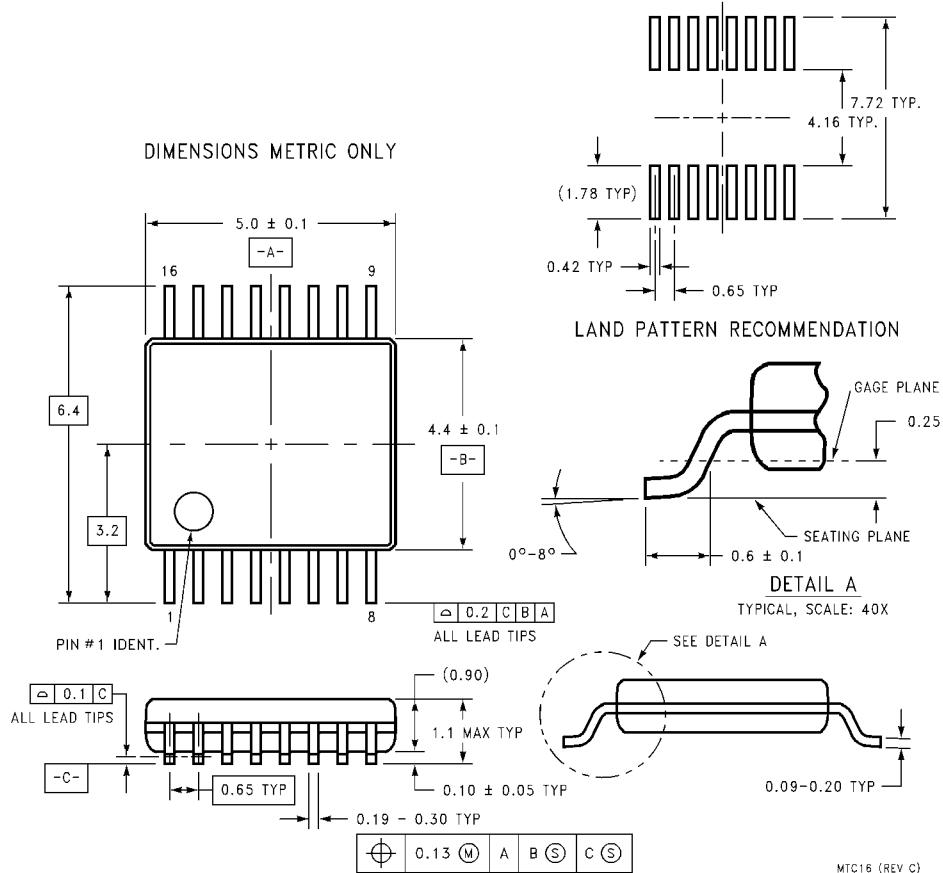


16-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-012, 0.150" Narrow Package Number M16A



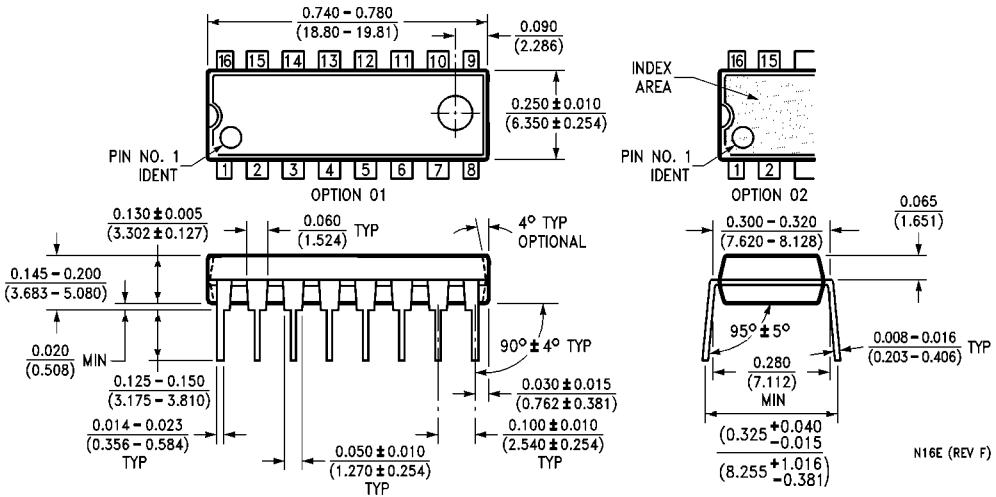
16-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide Package Number M16D

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



**16-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide
Package Number MTC16**

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



16-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300" Wide
Package Number N16E

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